# **OSRAM** LR ETSF.01 **Datasheet**





#### Power TOPLED™

## LR ETSF.01

PowerTOPLED, a powerful member of the PLCC family. Our long-established and well-known product is entering a new generation. It is tailored for rear light clusters such as stop light and indicators on vehicles.



The PowerTOPLED™.01 is the new generation of the Power TOPLED™ family, upgraded with the latest InGaAIP Chip technology from ams OSRAM. The first released devices of the new generation were the Lx E67F.01 with resin casting. Now, the silicone-casted devices Lx ETSF.01 and Lx E6SF.01 are following.



#### **Applications**

- Functional Illumination

- Static Signaling

#### **Features**

- Package: white PLCC-4 package, colorless clear silicone resin
- Chip technology: Thinfilm
- Typ. Radiation: 120° (Lambertian emitter)
- Color:  $\lambda_{dom}$  = 625 nm (• red)
- Corrosion Robustness Class: 3B
- Qualifications: AEC-Q102 Qualified
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)



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Luminous Intensity 1) Ordering Code Type

 $I_F = 50 \text{ mA}$ 

LR ETSF.01-7B8C-46-G3R3 2240 ... 4500 mcd Q65113A8813



| Maximum Ratings   |                 |              |                  |
|---|-----------------|--------------|------------------|
| Parameter   | Symbol          |              | Values           |
| Operating Temperature   | T <sub>op</sub> | min.<br>max. | -40 °C<br>110 °C |
| Storage Temperature   | $T_{stg}$       | min.<br>max. | -40 °C<br>110 °C |
| Junction Temperature  | T <sub>j</sub>  | max.         | 125 °C           |
| Junction Temperature for short time applications*                                 | T <sub>i</sub>  | max.         | 150 °C           |
| Forward current T <sub>S</sub> = 25 °C  | I <sub>F</sub>  | min.<br>max. | 3 mA<br>70 mA    |
| Forward current pulsed $t \le 10 \ \mu s; D \le 0.005 \ \%; T_s = 25 \ ^{\circ}C$ | F pulse         | max.         | 100 mA           |
| Reverse voltage <sup>2)</sup> T <sub>S</sub> = 25 °C                              | $V_R$           | max.         | 12 V             |
| ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)               | $V_{ESD}$       |              | 2 kV             |

<sup>\*</sup> The median lifetime (L70/B50) for Tj = 150°C is 100h.



#### **Characteristics**

 $I_F$  = 50 mA;  $T_S$  = 25 °C

| Parameter  | Symbol                  |      | Values      |
|--|-------------------------|------|-------------|
| Peak Wavelength  | $\lambda_{\sf peak}$    | typ. | 634 nm      |
| Dominant Wavelength 3)                                       | $\lambda_{\sf dom}$     | min. | 620 nm      |
| $I_F = 50 \text{ mA}$  | 33                      | typ. | 625 nm      |
|  |                         | max. | 630 nm      |
| Spectral Bandwidth at 50% I <sub>rel,max</sub>               | $\Delta \lambda$        | typ. | 19 nm       |
| Viewing angle at 50% $\rm I_{_{\rm V}}$                      | 2φ                      | typ. | 120 °       |
| Forward Voltage 4)   | $V_{F}$                 | min. | 1.90 V      |
| $I_F = 50 \text{ mA}$  | •                       | typ. | 2.15 V      |
|  |                         | max. | 2.50 V      |
| Reverse current 2)   | I <sub>R</sub>          | typ. | 0.01 µA     |
| V <sub>R</sub> = 12 V  | · ·                     | max. | 10 µA       |
| Temperature Coefficient of Peak Wavelength -10°C ≤ T ≤ 100°C | $TC_{_{\lambdapeak}}$   | typ. | 0.14 nm / K |
| Real thermal resistance junction/solderpoint 5)              | R <sub>thJS real</sub>  | typ. | 70 K / W    |
| · · · · · · · · · · · · · · · · · · ·                        | uioo reai               | max. | 95 K / W    |
| Electrical thermal resistance junction/solderpoint 5)        | R <sub>thJS elec.</sub> | typ. | 39 K / W    |
| with efficiency $\eta_e$ = 44 %                              | 4100 0100.              | max. | 53 K / W    |



## **Brightness Groups**

| Group | Luminous Intensity 1) I <sub>F</sub> = 50 mA | Luminous Intensity. 1) I <sub>F</sub> = 50 mA | Luminous Flux <sup>6)</sup><br>I <sub>=</sub> = 50 mA |
|-------|--|---|---|
|       | min.   | max.  | typ.  |
|       | $I_{v}$                                      | $I_{v}$                                       | $\Phi_{V}$  |
| 7B    | 2240 mcd                                     | 2500 mcd                                      | 7110 mlm  |
| 8B    | 2500 mcd                                     | 2800 mcd                                      | 7950 mlm  |
| 5C    | 2800 mcd                                     | 3150 mcd                                      | 8925 mlm  |
| 6C    | 3150 mcd                                     | 3550 mcd                                      | 10050 mlm   |
| 7C    | 3550 mcd                                     | 4000 mcd                                      | 11325 mlm   |
| 8C    | 4000 mcd                                     | 4500 mcd                                      | 12750 mlm   |

## **Forward Voltage Groups**

| Group | Forward Voltage <sup>4)</sup> I <sub>F</sub> = 50 mA min. | Forward Voltage <sup>4)</sup> I <sub>F</sub> = 50 mA max. |  |
|-------|---|---|--|
| G3    | 1.90 V  | 2.05 V  |  |
| K3    | 2.05 V  | 2.20 V  |  |
| N3    | 2.20 V  | 2.35 V  |  |
| R3    | 2.35 V  | 2.50 V  |  |

## **Wavelength Groups**

| Group Dominant Wavelength $^{3)}$ $I_F = 50 \text{ mA}$ min. |                     | Dominant Wavelength <sup>3)</sup> I <sub>F</sub> = 50 mA max. |  |
|--|---------------------|---|--|
|  | $\lambda_{\sf dom}$ | $\lambda_{\sf dom}$   |  |
| 4  | 620 nm              | 624 nm  |  |
| 5  | 624 nm              | 627 nm  |  |
| 6  | 627 nm              | 630 nm  |  |

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### **Group Name on Label**

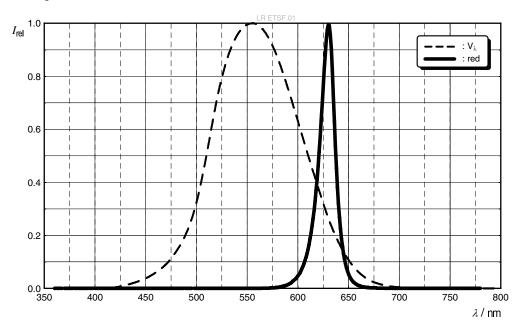
Example: 5C-4-G3

| Brightness | Wavelength | Forward Voltage |
|------------|------------|-----------------|
| 5C         | 4          | G3              |



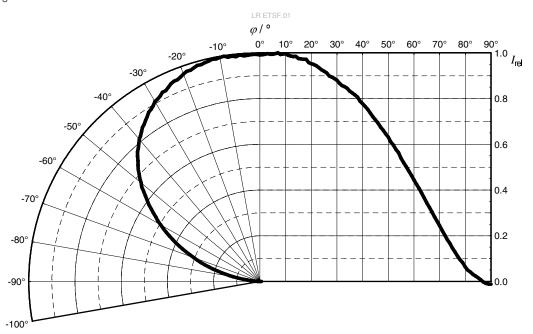
#### Relative Spectral Emission 6)

 $I_{rel}$  = f ( $\lambda$ );  $I_{F}$  = 50 mA;  $T_{S}$  = 25 °C



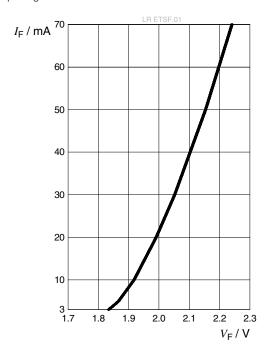
### Radiation Characteristics 6)

 $I_{rel} = f(\phi); T_S = 25 °C$ 



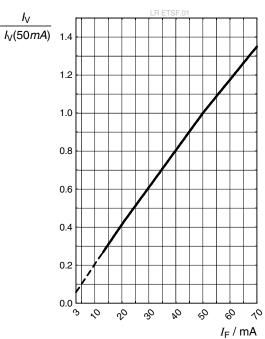
## Forward current 6)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



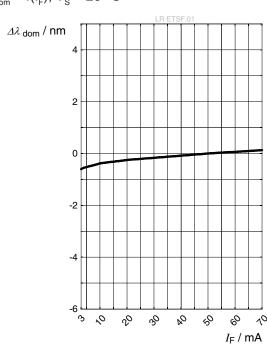
### Relative Luminous Intensity 6), 7)

$$I_{v}/I_{v}(50 \text{ mA}) = f(I_{F}); T_{S} = 25 \text{ °C}$$



## Dominant Wavelength 6)

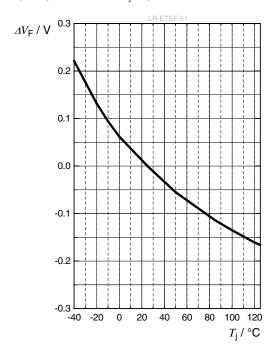
$$\Delta\lambda_{dom} = f(I_F); T_S = 25 \text{ }^{\circ}\text{C}$$





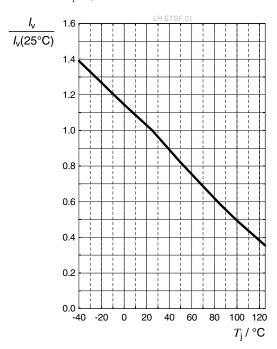
#### Forward Voltage 6)

$$\Delta V_F = V_F - V_F (25 \ ^{\circ}C) = f(T_j); I_F = 50 \ mA$$



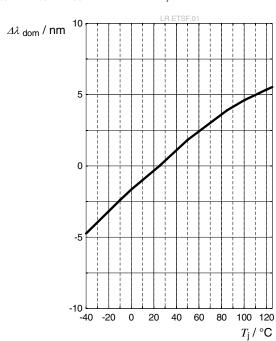
### Relative Luminous Intensity 6)

$$I_{v}/I_{v}(25 \text{ °C}) = f(T_{i}); I_{F} = 50 \text{ mA}$$



## **Dominant Wavelength** 6)

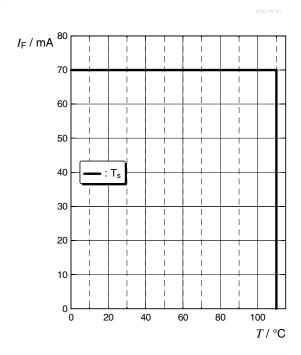
$$\Delta\lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25~^{\circ}C) = f(T_{j}); I_{F} = 50~mA$$





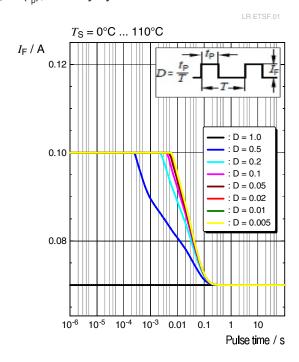
#### Max. Permissible Forward Current 5)

 $I_F = f(T)$ 



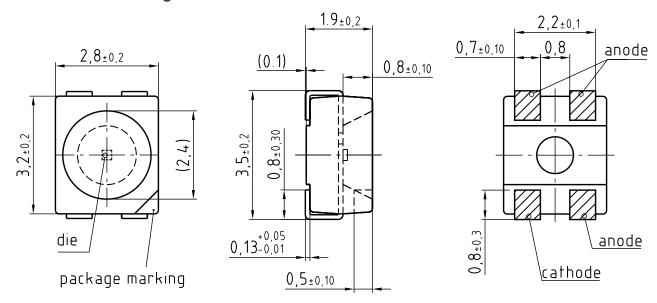
## Permissible Pulse Handling Capability

 $I_F = f(t_p)$ ; D: Duty cycle





### **Dimensional Drawing** 8)



C63062-A3861-A6..-05

#### **Further Information:**

Approximate Weight: 30.0 mg

Package marking: Cathode

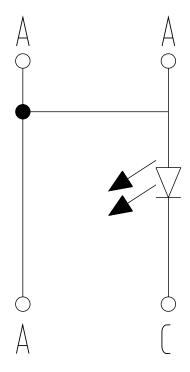
Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H<sub>2</sub>S / 14 days (stricter than IEC

60068-2-43)

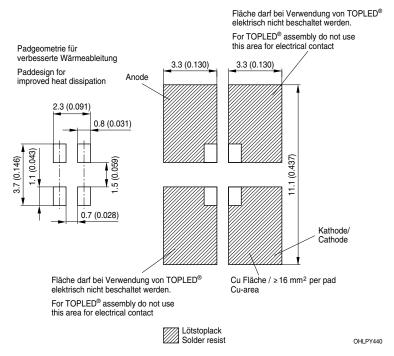


## **Electrical Internal Circuit**





#### Recommended Solder Pad 8)

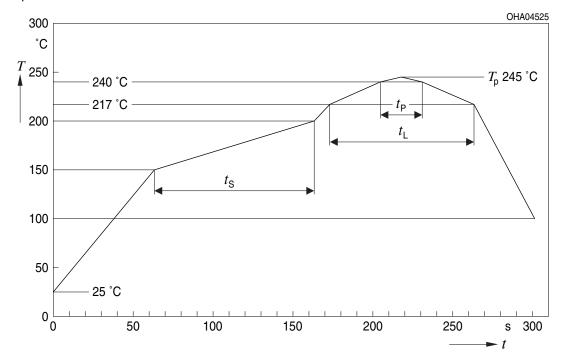


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



#### **Reflow Soldering Profile**

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



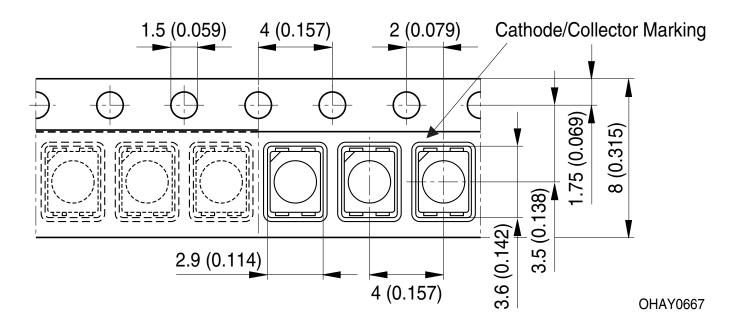
| Profile Feature   | Symbol                         | Pb      | -Free (SnAgCu) Ass | Unit    |     |
|---|--------------------------------|---------|--------------------|---------|-----|
|   |                                | Minimum | Recommendation     | Maximum |     |
| Ramp-up rate to preheat*)   |                                |         | 2                  | 3       | K/s |
| 25 °C to 150 °C   |                                |         |                    |         |     |
| Time t <sub>s</sub>   | $t_s$                          | 60      | 100                | 120     | S   |
| $T_{Smin}$ to $T_{Smax}$  |                                |         |                    |         |     |
| Ramp-up rate to peak*)  |                                |         | 2                  | 3       | K/s |
| $T_{Smax}$ to $T_{P}$   |                                |         |                    |         |     |
| Liquidus temperature  | $T_{L}$                        |         | 217                |         | °C  |
| Time above liquidus temperature   | $t_{\scriptscriptstyle \perp}$ |         | 80                 | 100     | S   |
| Peak temperature  | $T_{P}$                        |         | 245                | 260     | °C  |
| Time within 5 °C of the specified peak temperature T <sub>P</sub> - 5 K | t <sub>P</sub>                 | 10      | 20                 | 30      | S   |
| Ramp-down rate* T <sub>p</sub> to 100 °C                                |                                |         | 3                  | 6       | K/s |
| Time 25 °C to T <sub>P</sub>  |                                |         |                    | 480     | S   |

All temperatures refer to the center of the package, measured on the top of the component

<sup>\*</sup> slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

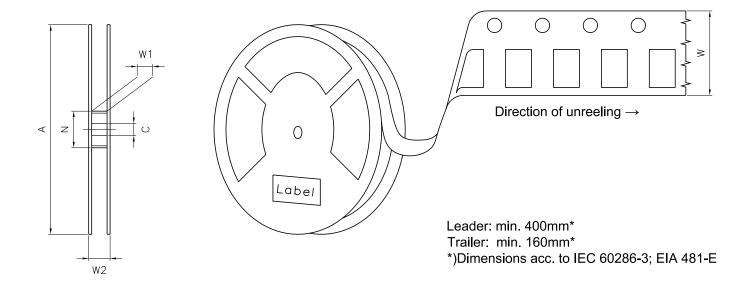


### Taping 8)





### Tape and Reel 9)

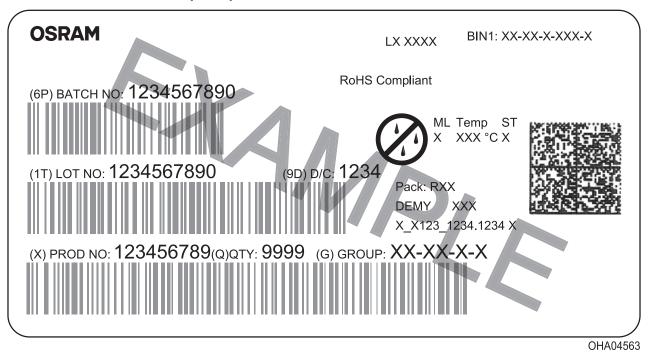


#### **Reel Dimensions**

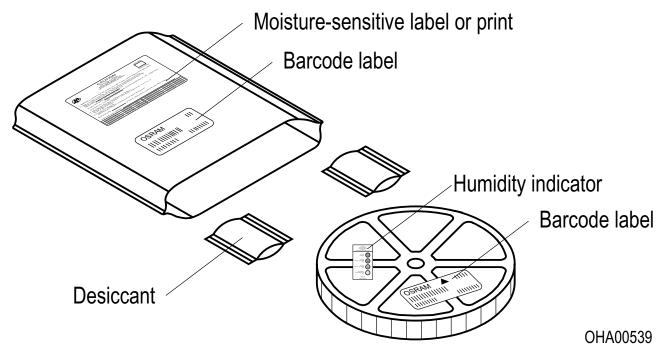
| Α      | W                  | $N_{\min}$ | $W_1$      | $W_{2 max}$ | Pieces per PU |
|--------|--------------------|------------|------------|-------------|---------------|
| 180 mm | 8 + 0.3 / - 0.1 mm | 60 mm      | 8.4 + 2 mm | 14.4 mm     | 2000          |



#### **Barcode-Product-Label (BPL)**



### Dry Packing Process and Materials 8)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

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#### **Notes**

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class exempt group (exposure time 10000 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit https://ams-osram.com/support/application-notes



#### Disclaimer

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

#### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

#### Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



#### Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ±8 % and an expanded uncertainty of ±11 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Wavelength: The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k =
- Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- 5) Thermal Resistance: Rth max is based on statistic values (6 $\sigma$ ) used for Derating.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 9) Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

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#### **Revision History**

| Version | Date       | Change          |
|---------|------------|-----------------|
| 1.0     | 2025-01-28 | Initial Version |
| 1.1     | 2025-12-08 | Description     |



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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